

Dual General Purpose Transistors

NPN Duals

BC846BDW1, BC847BDW1, BC848CDW1

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-363/SC-88 which is designed for low power surface mount applications.

Features

- S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	BC846	BC847	BC848	Unit
Collector - Emitter Voltage	V _{CEO}	65	45	30	V
Collector - Base Voltage	V _{CBO}	80	50	30	V
Emitter - Base Voltage	V _{EBO}	6.0	6.0	5.0	V
Collector Current – Continuous	I _C	100	100	100	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

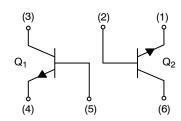
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation Per Device FR-5 Board (Note 1) T _A = 25°C	P _D	380 250	mW mW
Derate Above 25°C		3.0	mW/°C
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	328	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

1. FR-5 = 1.0 x 0.75 x 0.062 in



SOT-363/SC-88 CASE 419B STYLE 1



MARKING DIAGRAM



1x = Specific Device Code

x = B, F, G, L

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•	•	•
Collector – Emitter Breakdown Voltage (I _C = 10 mA) BC846 BC847 BC848	V _{(BR)CEO}	65 45 30	- - -	- - -	V
Collector – Emitter Breakdown Voltage (I _C = 10 μA, V _{EB} = 0) BC846 BC847 BC848	V _{(BR)CES}	80 50 30	- - -	- - -	V
Collector – Base Breakdown Voltage (I _C = 10 μA) BC846 BC847 BC848	V _(BR) CBO	80 50 30	- - -	- - -	V
Emitter – Base Breakdown Voltage (I _E = 1.0 μA) BC846 BC847 BC848	V _{(BR)EBO}	6.0 6.0 5.0	- - -	- - -	V
Collector Cutoff Current (V _{CB} = 30 V) (V _{CB} = 30 V, T _A = 150°C)	I _{CBO}	- -	- -	15 5.0	nA μA
ON CHARACTERISTICS					
DC Current Gain $ \begin{aligned} &(I_C = 10 \; \mu A, V_{CE} = 5.0 \; V) \\ &BC846B, BC847B \\ &BC847C, BC848C \\ &(I_C = 2.0 \; mA, V_{CE} = 5.0 \; V) \\ &BC846B, BC847B \end{aligned} $	h _{FE}	- - 200	150 270 290	- - 450	-
BC847C, BC848C		420	520	800	
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$)	V _{CE(sat)}	- -	- -	0.25 0.6	V
Base – Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA) (I_C = 100 mA, I_B = 5.0 mA)	V _{BE(sat)}	- -	0.7 0.9	- -	V
Base – Emitter Voltage ($I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$) ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$)	V _{BE(on)}	580 -	660 -	700 770	mV
SMALL-SIGNAL CHARACTERISTICS	•			•	
Current – Gain – Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$)	f _T	100	-	-	MHz
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	C _{obo}	-	-	4.5	pF
Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 Vdc, R _S = 2.0 k Ω ,f = 1.0 kHz, BW = 200 Hz)	NF	_	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS - BC846BDW1

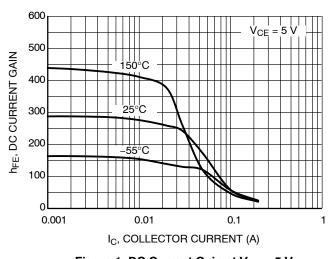


Figure 1. DC Current Gain at V_{CE} = 5 V

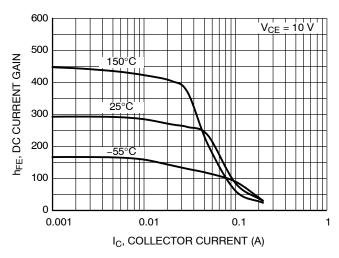


Figure 2. DC Current Gain at $V_{CE} = 10 \text{ V}$

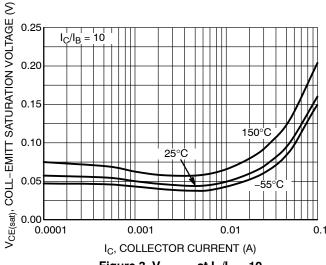


Figure 3. $V_{CE(sat)}$ at $I_C/I_B = 10$

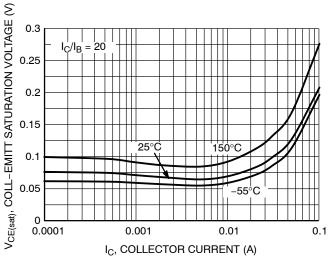
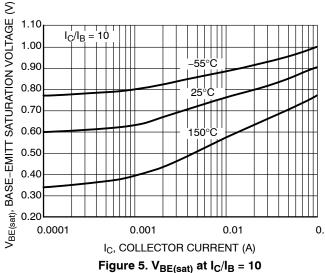


Figure 4. $V_{CE(sat)}$ at $I_C/I_B = 20$



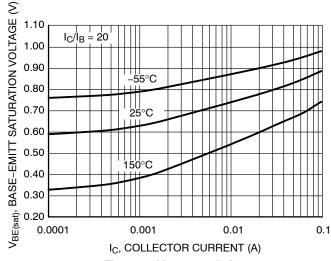


Figure 6. $V_{BE(sat)}$ at $I_C/I_B = 20$

TYPICAL CHARACTERISTICS - BC846BDW1

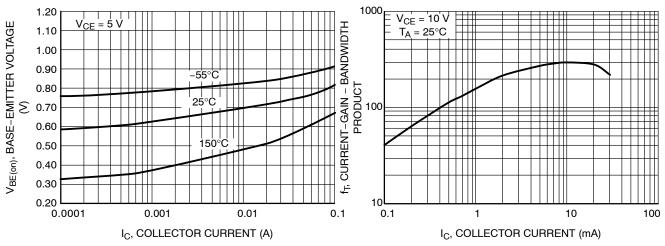


Figure 7. V_{BE(on)} at V_{CE} = 5 V

Figure 8. Current - Gain - Bandwidth Product

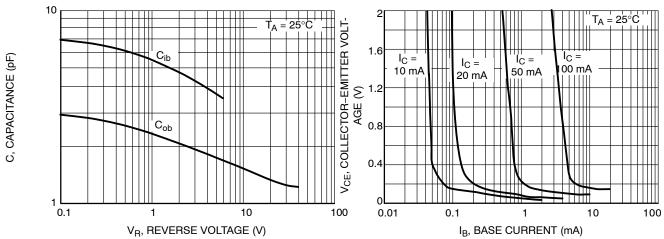


Figure 9. Capacitances

Figure 10. Collector Saturation Region

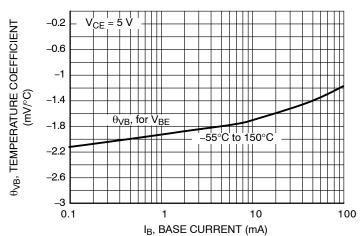
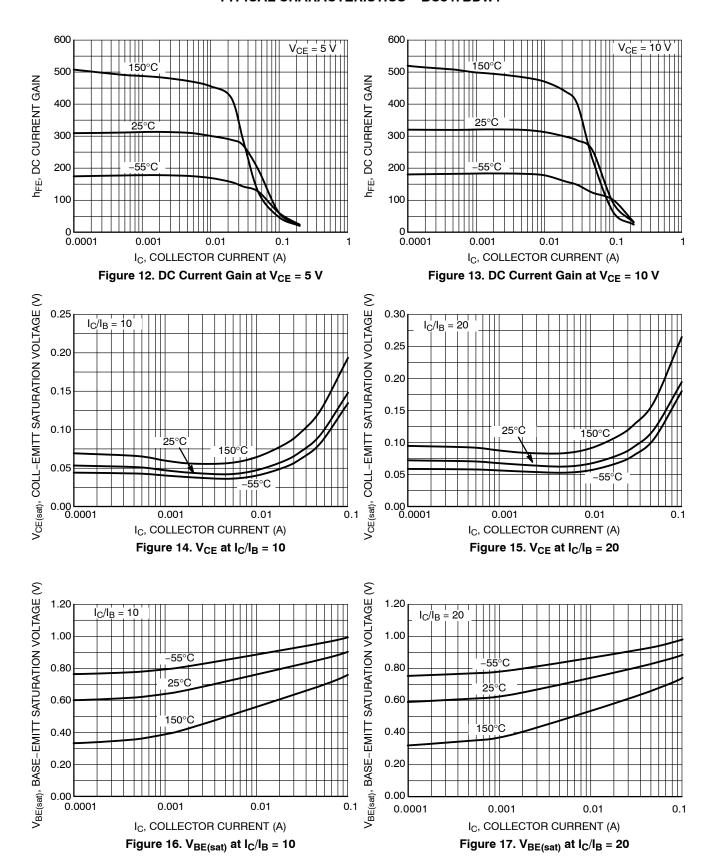
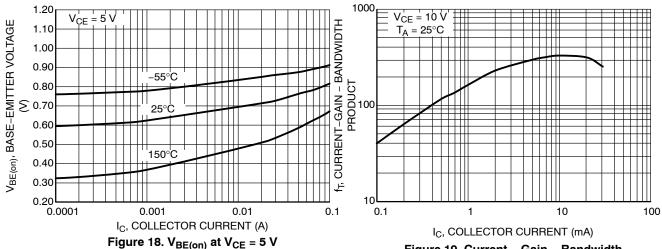


Figure 11. Base-Emitter Temperature Coefficient

TYPICAL CHARACTERISTICS - BC847BDW1



TYPICAL CHARACTERISTICS - BC847BDW1



re 18. V_{BE(on)} at V_{CE} = 5 V Figure 19. Current – Gain – Bandwidth Product

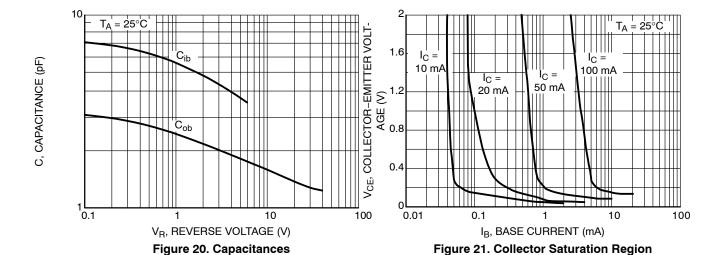


Figure 22. Base-Emitter Temperature Coefficient

TYPICAL CHARACTERISTICS - BC848CDW1

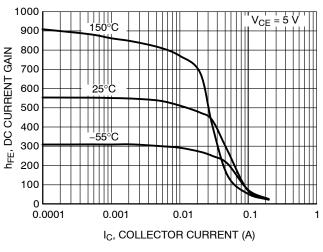


Figure 23. DC Current Gain at $V_{CE} = 5 \text{ V}$

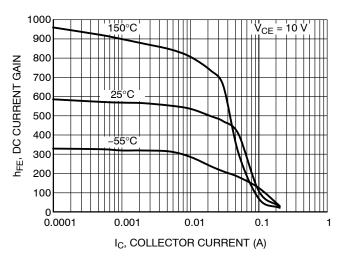
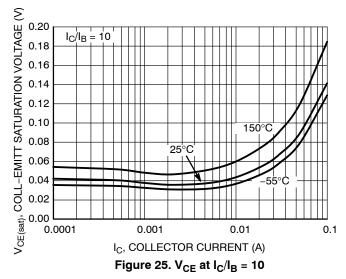


Figure 24. DC Current Gain at V_{CE} = 10 V



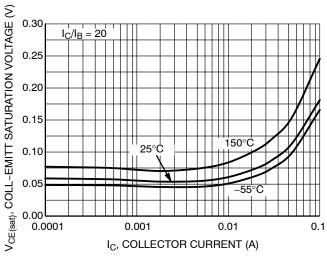


Figure 26. V_{CE} at $I_C/I_B = 20$

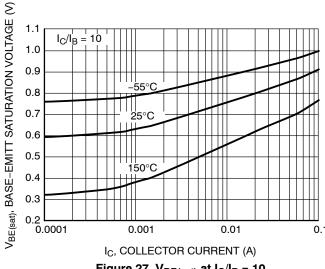


Figure 27. $V_{BE(sat)}$ at $I_C/I_B = 10$

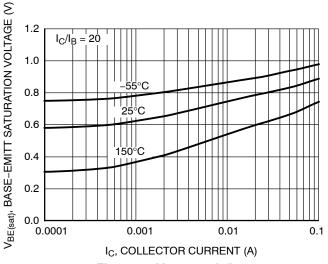


Figure 28. $V_{BE(sat)}$ at $I_C/I_B = 20$

TYPICAL CHARACTERISTICS - BC848CDW1

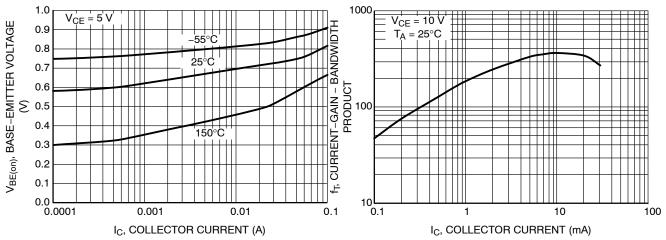


Figure 29. $V_{BE(on)}$ at $V_{CE} = 5 \text{ V}$

Figure 30. Current – Gain – Bandwidth Product

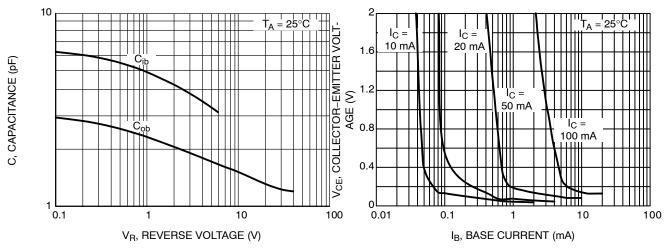


Figure 31. Capacitances

Figure 32. Collector Saturation Region

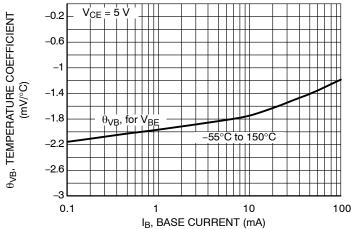


Figure 33. Base-Emitter Temperature Coefficient

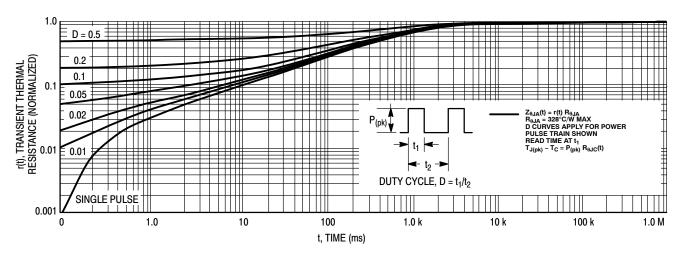


Figure 34. Thermal Response

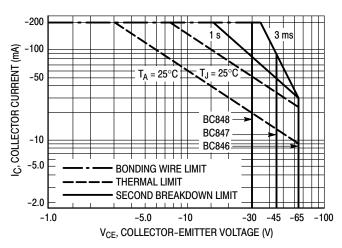


Figure 35. Active Region Safe Operating Area

The safe operating area curves indicate I_C–V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 35 is based upon $T_{J(pk)} = 150^{\circ}\text{C}$; T_{C} or T_{A} is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 34. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

ORDERING INFORMATION

Device	Markings	Package	Shipping [†]
BC846BDW1T1G	1B	SOT-363 (Pb-Free)	3,000 / Tape & Reel
SBC846BDW1T1G*	1B	SOT-363 (Pb-Free)	3,000 / Tape & Reel
BC847BDW1T1G	1F	SOT-363 (Pb-Free)	3,000 / Tape & Reel
SBC847BDW1T1G*	1F	SOT-363 (Pb-Free)	3,000 / Tape & Reel
BC847BDW1T3G	1F	SOT-363 (Pb-Free)	10,000 / Tape & Reel
SBC847BDW1T3G*	1F	SOT-363 (Pb-Free)	10,000 / Tape & Reel
NSVBC847BDW1T2G*	1F	SOT-363 (Pb-Free)	3,000 / Tape & Reel
BC847CDW1T1G	1G	SOT-363 (Pb-Free)	3,000 / Tape & Reel
SBC847CDW1T1G*	1G	SOT-363 (Pb-Free)	3,000 / Tape & Reel
BC848CDW1T1G	1L	SOT-363 (Pb-Free)	3,000 / Tape & Reel
NSVBC848CDW1T1G*	1L	SOT-363 (Pb-Free)	3,000 / Tape & Reel

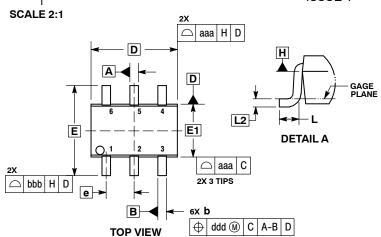
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

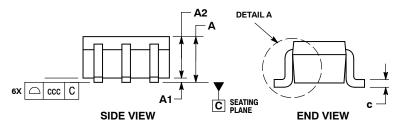
^{*}S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



SC-88/SC70-6/SOT-363 CASE 419B-02 **ISSUE Y**

DATE 11 DEC 2012





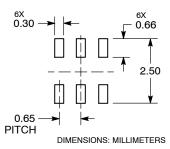
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M. 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H. DIMENSIONS b AND B ARE DETERMINED AT DATUM H. DIMENSIONS b AND C APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.

- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION 6 AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10			0.043
A1	0.00		0.10	0.000		0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
Е	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2		0.15 BS	C	0.006 BSC		
aaa	0.15			0.006		
bbb	0.30			0.012		
ccc	0.10			0.004		
ddd	0.10				0.004	

RECOMMENDED



SOLDERING FOOTPRINT*

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code* = Pb-Free Package

(Note: Microdot may be in either location)

- *Date Code orientation and/or position may vary depending upon manufacturing location.
- *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

DATE 11 DEC 2012

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13: PIN 1. ANODE 2. N/C 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 14: PIN 1. VREF 2. GND 3. GND 4. IOUT 5. VEN 6. VCC	STYLE 15: PIN 1. ANODE 1 2. ANODE 2 3. ANODE 3 4. CATHODE 3 5. CATHODE 2 6. CATHODE 1	STYLE 16: PIN 1. BASE 1 2. EMITTER 2 3. COLLECTOR 2 4. BASE 2 5. EMITTER 1 6. COLLECTOR 1	STYLE 17: PIN 1. BASE 1 2. EMITTER 1 3. COLLECTOR 2 4. BASE 2 5. EMITTER 2 6. COLLECTOR 1	STYLE 18: PIN 1. VIN1 2. VCC 3. VOUT2 4. VIN2 5. GND 6. VOUT1
STYLE 19: PIN 1. I OUT 2. GND 3. GND 4. V CC 5. V EN 6. V REF	STYLE 20: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR	STYLE 21: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. N/C 6. CATHODE 1	STYLE 22: PIN 1. D1 (i) 2. GND 3. D2 (i) 4. D2 (c) 5. VBUS 6. D1 (c)	STYLE 23: PIN 1. Vn 2. CH1 3. Vp 4. N/C 5. CH2 6. N/C	STYLE 24: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE
STYLE 25: PIN 1. BASE 1 2. CATHODE 3. COLLECTOR 2 4. BASE 2 5. EMITTER 6. COLLECTOR 1	STYLE 26: PIN 1. SOURCE 1 2. GATE 1 3. DRAIN 2 4. SOURCE 2 5. GATE 2 6. DRAIN 1	STYLE 27: PIN 1. BASE 2 2. BASE 1 3. COLLECTOR 1 4. EMITTER 1 5. EMITTER 2 6. COLLECTOR 2	STYLE 28: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6. DRAIN	STYLE 29: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE/ANODE 6. CATHODE	STYLE 30: PIN 1. SOURCE 1 2. DRAIN 2 3. DRAIN 2 4. SOURCE 2 5. GATE 1 6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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